

# SWITCHMODE Power Rectifiers

## MBR10100MFS, NRVB10100MFS

### Features

- Low Power Loss / High Efficiency
- New Package Provides Capability of Inspection and Probe After Board Mounting
- Guardring for Stress Protection
- Low Forward Voltage Drop
- 175°C Operating Junction Temperature
- Wettable Flacks Option Available
- NRVB Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These are Pb-Free Devices

### Mechanical Characteristics:

- Case: Epoxy, Molded
- Epoxy Meets Flammability Rating UL 94-0 @ 0.125 in.
- Lead Finish: 100% Matte Sn (Tin)
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Device Meets MSL 1 Requirements

### MAXIMUM RATINGS

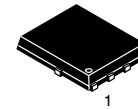
| Rating  | Symbol                          | Value       | Unit |
|---|---------------------------------|-------------|------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage                      | $V_{RRM}$<br>$V_{RWM}$<br>$V_R$ | 100         | V    |
| Average Rectified Forward Current<br>(Rated $V_R$ , $T_C = 165^\circ\text{C}$ )                             | $I_{F(AV)}$                     | 10          | A    |
| Peak Repetitive Forward Current,<br>(Rated $V_R$ , Square Wave,<br>20 kHz, $T_C = 163^\circ\text{C}$ )      | $I_{FRM}$                       | 20          | A    |
| Non-Repetitive Peak Surge Current<br>(Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz) | $I_{FSM}$                       | 150         | A    |
| Storage Temperature Range   | $T_{stg}$                       | -65 to +175 | °C   |
| Operating Junction Temperature  | $T_J$                           | -55 to +175 | °C   |
| Unclamped Inductive Switching Energy<br>(10 mH Inductor, Non-repetitive)                                    | $E_{AS}$                        | 75          | mJ   |
| ESD Rating (Human Body Model)   |                                 | 3B          |      |
| ESD Rating (Machine Model)  |                                 | M4          |      |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

NOTE: The heat generated must be less than the thermal conductivity from Junction-to-Ambient:  $dPD/dT_J < 1/RJA$ .

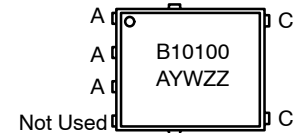
## SCHOTTKY BARRIER RECTIFIERS 10 AMPERES 100 VOLTS

1,2,3  5,6



SO-8 FLAT LEAD  
CASE 488AA  
STYLE 2

### MARKING DIAGRAM



B10100 = Specific Device Code  
A = Assembly Location  
Y = Year  
W = Work Week  
ZZ = Lot Traceability

### ORDERING INFORMATION

| Device          | Package              | Shipping†             |
|-----------------|----------------------|-----------------------|
| NRVB10100MFST1G | SO-8 FL<br>(Pb-Free) | 1500 /<br>Tape & Reel |

### DISCONTINUED (Note 1)

|                 |                      |                       |
|-----------------|----------------------|-----------------------|
| MBR10100MFST1G  | SO-8 FL<br>(Pb-Free) | 1500 /<br>Tape & Reel |
| MBR10100MFST3G  |                      | 5000 /<br>Tape & Reel |
| NRVB10100MFST3G |                      |                       |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

1. **DISCONTINUED:** These devices are not recommended for new design. Please contact your onsemi representative for information. The most current information on these devices may be available on [www.onsemi.com](http://www.onsemi.com).

# MBR10100MFS, NRVB10100MFS

## THERMAL CHARACTERISTICS

| Characteristic  | Symbol          | Typ | Max | Unit |
|---|-----------------|-----|-----|------|
| Thermal Resistance, Junction-to-Case, Steady State<br>(Assumes 600 mm <sup>2</sup> 1 oz. copper bond pad, on a FR4 board) | $R_{\theta JC}$ | –   | 1.8 | °C/W |

## ELECTRICAL CHARACTERISTICS

|   |       |              |              |    |
|---|-------|--------------|--------------|----|
| Instantaneous Forward Voltage (Note 1)<br>( $i_F = 10$ Amps, $T_J = 125^\circ\text{C}$ )<br>( $i_F = 10$ Amps, $T_J = 25^\circ\text{C}$ ) | $V_F$ | 0.64<br>0.80 | 0.88<br>0.95 | V  |
| Instantaneous Reverse Current (Note 1)<br>(Rated dc Voltage, $T_J = 125^\circ\text{C}$ )<br>(Rated dc Voltage, $T_J = 25^\circ\text{C}$ ) | $i_R$ | 4<br>0.003   | 13<br>0.100  | mA |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width = 300  $\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

## TYPICAL CHARACTERISTICS

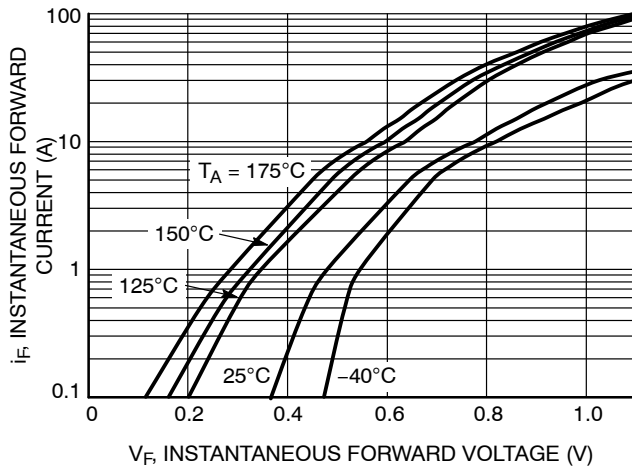


Figure 1. Typical Instantaneous Forward Characteristics

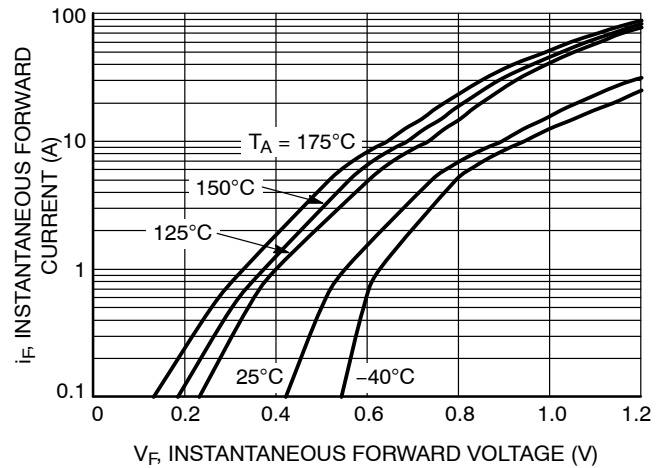


Figure 2. Maximum Instantaneous Forward Characteristics

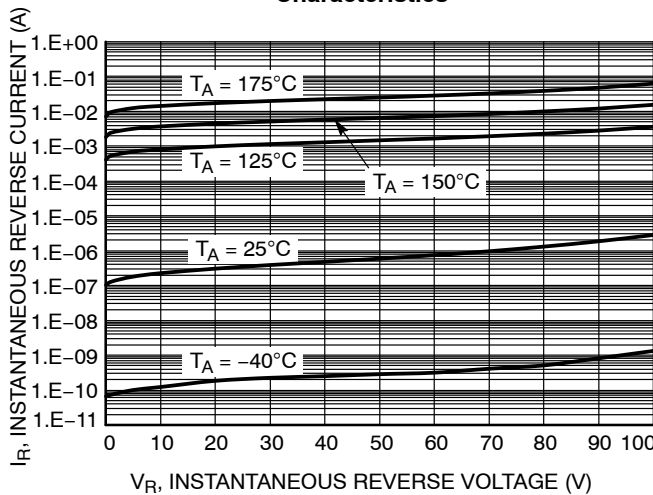


Figure 3. Typical Reverse Characteristics

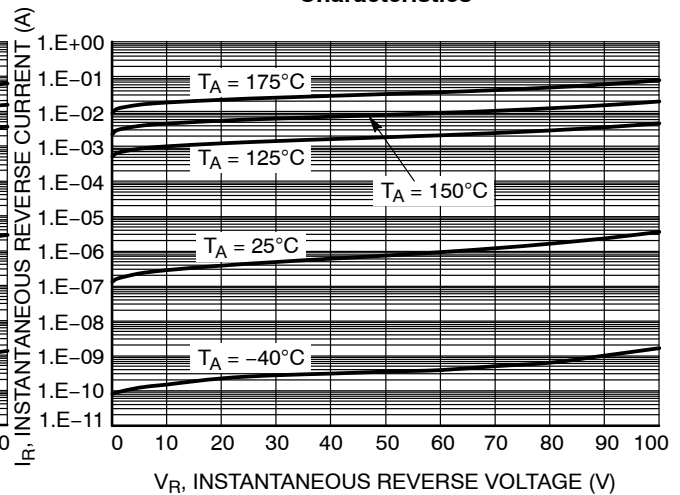


Figure 4. Maximum Reverse Characteristics

# MBR10100MFS, NRVB10100MFS

## TYPICAL CHARACTERISTICS

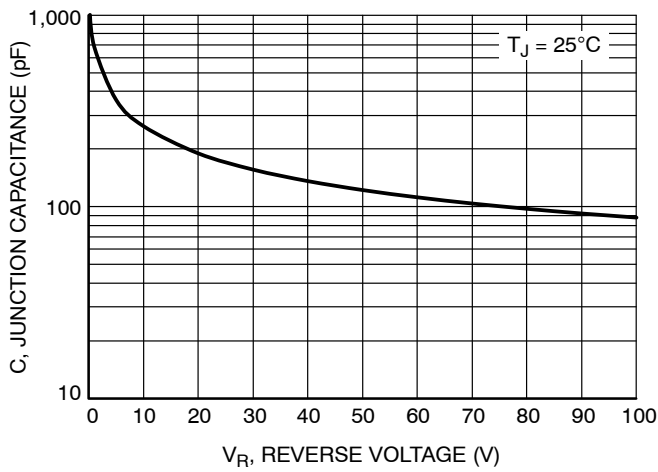


Figure 5. Typical Junction Capacitance

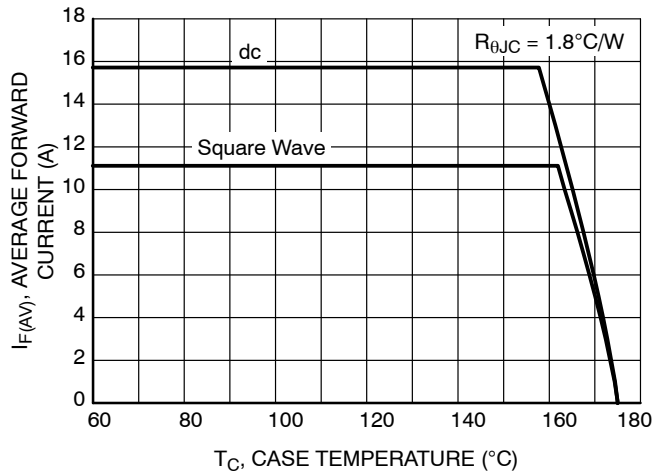


Figure 6. Current Derating TO-220AB

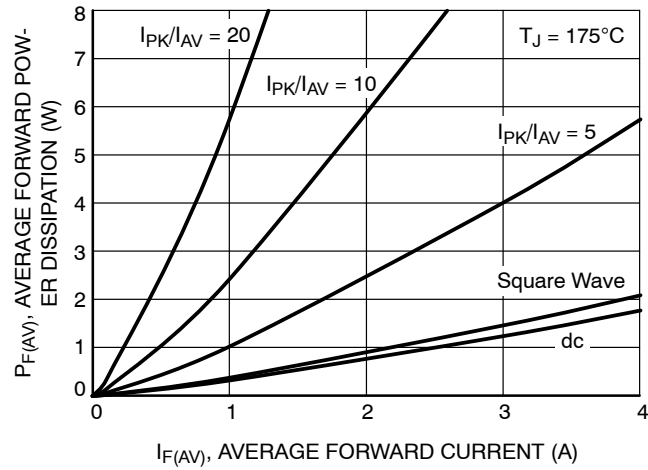


Figure 7. Forward Power Dissipation

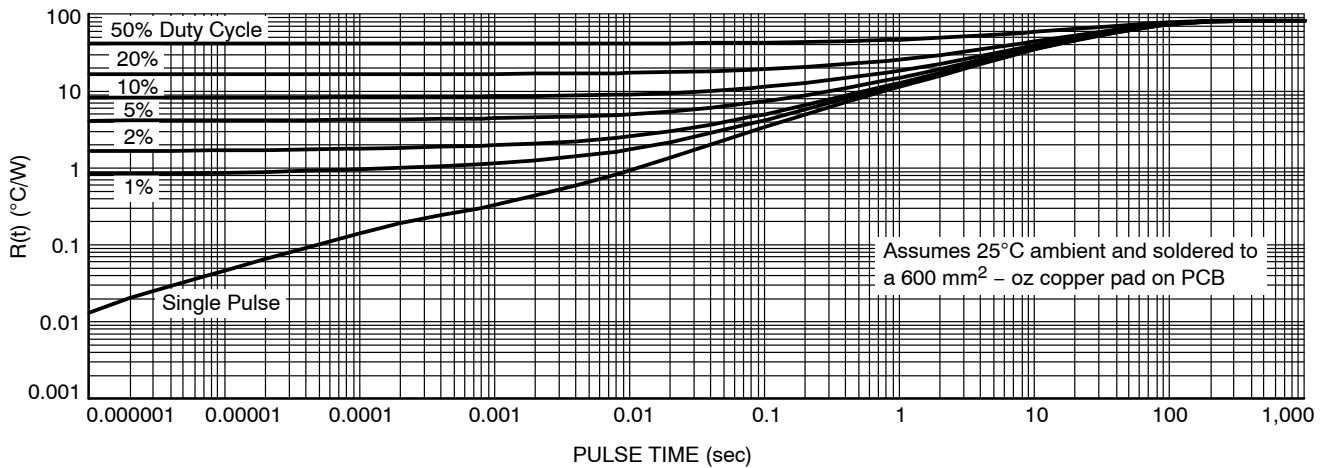
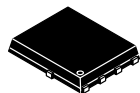


Figure 8. Thermal Response



SCALE 2:1

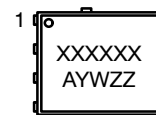
**DFN5 5x6, 1.27P**  
**(SO-8FL)**  
**CASE 488AA**  
**ISSUE N**

DATE 25 JUN 2018

## NOTES:

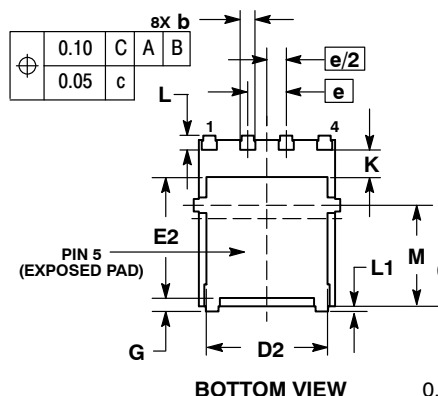
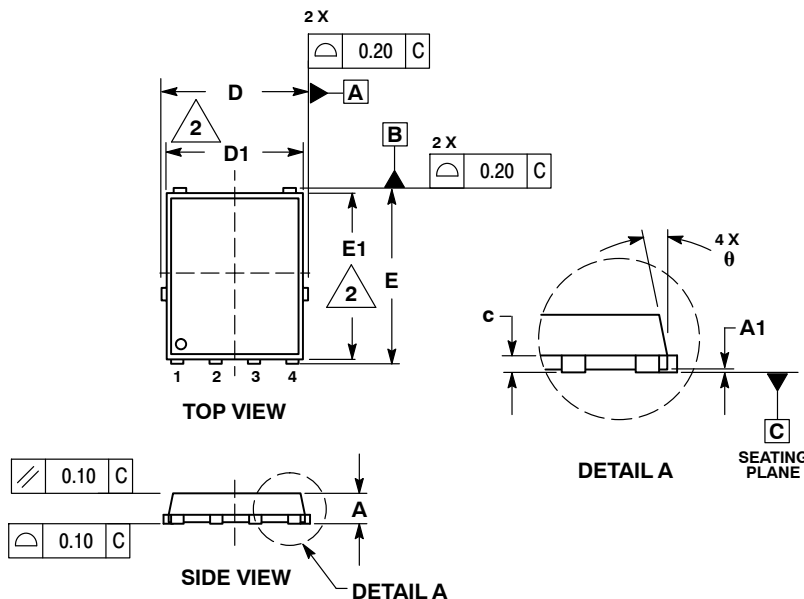
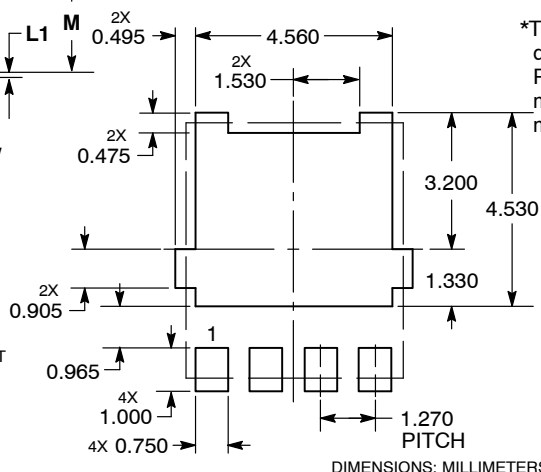
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION D1 AND E1 DO NOT INCLUDE MOLD FLASH PROTRUSIONS OR GATE BURRS.

| DIM | MILLIMETERS |       |      |
|-----|-------------|-------|------|
|     | MIN         | NOM   | MAX  |
| A   | 0.90        | 1.00  | 1.10 |
| A1  | 0.00        | ---   | 0.05 |
| b   | 0.33        | 0.41  | 0.51 |
| c   | 0.23        | 0.28  | 0.33 |
| D   | 5.00        | 5.15  | 5.30 |
| D1  | 4.70        | 4.90  | 5.10 |
| D2  | 3.80        | 4.00  | 4.20 |
| E   | 6.00        | 6.15  | 6.30 |
| E1  | 5.70        | 5.90  | 6.10 |
| E2  | 3.45        | 3.65  | 3.85 |
| e   | 1.27 BSC    |       |      |
| G   | 0.51        | 0.575 | 0.71 |
| K   | 1.20        | 1.35  | 1.50 |
| L   | 0.51        | 0.575 | 0.71 |
| L1  | 0.125 REF   |       |      |
| M   | 3.00        | 3.40  | 3.80 |
| θ   | 0°          | ---   | 12°  |

**GENERIC**  
**MARKING DIAGRAM\***


XXXXXX = Specific Device Code  
A = Assembly Location  
Y = Year  
W = Work Week  
ZZ = Lot Traceability

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.


**RECOMMENDED**  
**SOLDERING FOOTPRINT\***


DIMENSIONS: MILLIMETERS

STYLE 1:  
PIN 1. SOURCE  
2. SOURCE  
3. SOURCE  
4. GATE  
5. DRAIN

STYLE 2:  
PIN 1. ANODE  
2. ANODE  
3. ANODE  
4. NO CONNECT  
5. CATHODE

\*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

|                         |                                 |  |
|-------------------------|---------------------------------|--|
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| <b>DESCRIPTION:</b>     | <b>DFN5 5x6, 1.27P (SO-8FL)</b> | <b>PAGE 1 OF 1</b>   |

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